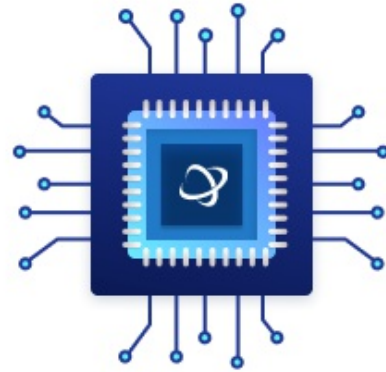


Silicon N-Channel MOS FET UHF Power Amplifier

|               |   |
|---------------|---|
| Manufacturers | <a href="#">Renesas Technology Corp</a> |
| Package/Case  | RP-8P                                   |
| Product Type  | Discrete Semiconductors                 |
| RoHS          |   |
| Lifecycle     |   |



Images are for reference only

Please submit RFQ for 2SK2595 or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

## General Description

2SK2595 is a power MOSFET transistor designed for high-current applications. Here are some of its features:

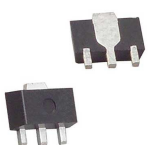
### Features

- Drain-source voltage: 600V
- Continuous drain current: 11A
- Low on-resistance: 0.38ohm
- Fast switching speed: 40ns

### Application

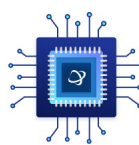
- IRF640N
- STP11NK40ZFP
- FQP11N60C
- 2SK2141
- 2SK2645

### Related Products



[2SK2596](#)

Renesas Technology Corp  
SOT89



[2SA812-T1B-A/S6](#)

Renesas Technology Corp



[HD74LV1G126ACME-E](#)

Renesas Technology Corp  
SOT-353



[RQA0009SXTL-E](#)

Renesas Technology Corp  
SOT-89



[M51996AFP](#)

Renesas Technology Corp  
SOP-16



[HSM123TL-E](#)

Renesas Technology Corp  
SOT23



[HA17431UA-TL-E](#)

Renesas Technology Corp  
SOT-89



[HA178L05UA-TL-E](#)

Renesas Technology Corp  
SOT-89